



PJS6603-AU

30V Complementary Enhancement Mode MOSFET

Voltage 30 / -30V **Current** 4.4 / -2.9A

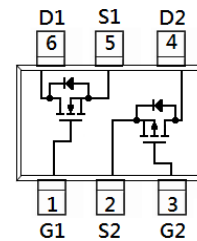
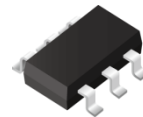
Features

- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-23 6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0005 ounces, 0.0142 grams

SOT-23 6L



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	N-Ch LIMIT	P-Ch LIMIT	UNITS
Drain-Source Voltage		V _{DS}	30	-30	V
Gate-Source Voltage		V _{GS}	+20	+20	V
Continuous Drain Current		I _D	4.4	-2.9	A
Pulsed Drain Current ^(Note 4)		I _{DM}	17.6	-11.6	A
Power Dissipation	T _a =25°C	P _D	1.25		W
	Derate above 25°C		10		mW/°C
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55~150		°C
Typical Thermal Resistance		R _{θJA}	100		°C/W
- Junction to Ambient ^(Note 3)					



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N-Channel Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1.0	1.37	2.1	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =4.4A	-	36	48	mΩ
		V _{GS} =4.5V, I _D =2.8A	-	52	70	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic (Note 5)						
Total Gate Charge	Q _g	V _{DS} =15V, I _D =4.4A, V _{GS} =10V (Note 1,2)	-	5.8	-	nC
Gate-Source Charge	Q _{gs}		-	1	-	
Gate-Drain Charge	Q _{gd}		-	1	-	
Input Capacitance	C _{iss}	V _{DS} =15V, V _{GS} =0V, f=1.0MHZ	-	235	-	pF
Output Capacitance	C _{oss}		-	36	-	
Reverse Transfer Capacitance	C _{rss}		-	24	-	
Turn-On Delay Time	td _(on)	V _{DD} =15V, I _D =4.4A, V _{GS} =10V, R _G =6Ω (Note 1,2)	-	3	-	ns
Turn-On Rise Time	tr		-	39	-	
Turn-Off Delay Time	td _(off)		-	23	-	
Turn-Off Fall Time	tf		-	28	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _s	---	-	-	1.5	A
Diode Forward Voltage	V _{SD}	I _S =1.0A, V _{GS} =0V	-	0.8	1.2	V

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%
2. Essentially independent of operating temperature typical characteristics.
3. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing



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P-Channel Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.3	-2.1	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-2.9A	-	94	110	mΩ
		V _{GS} =-4.5V, I _D =-1.9A	-	120	150	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic (Note 5)						
Total Gate Charge	Q _g	V _{DS} =-15V, I _D =-2.9A, V _{GS} =-10V (Note 1,2)	-	9.8	-	nC
Gate-Source Charge	Q _{gs}		-	1.5	-	
Gate-Drain Charge	Q _{gd}		-	2.2	-	
Input Capacitance	C _{iss}	V _{DS} =-15V, V _{GS} =0V, f=1.0MHZ	-	396	-	pF
Output Capacitance	C _{oss}		-	47	-	
Reverse Transfer Capacitance	C _{rss}		-	36	-	
Turn-On Delay Time	t _{d(on)}	V _{DD} =-15V, I _D =-2.9A, V _{GS} =-10V, R _G =6Ω (Note 1,2)	-	5	-	ns
Turn-On Rise Time	t _r		-	30	-	
Turn-Off Delay Time	t _{d(off)}		-	25	-	
Turn-Off Fall Time	t _f		-	8	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _s	---	-	-	-1.5	A
Diode Forward Voltage	V _{SD}	I _s =-1.0A, V _{GS} =0V	-	-0.85	-1.2	V

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%
2. Essentially independent of operating temperature typical characteristics.
3. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
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N-Channel TYPICAL CHARACTERISTIC CURVES

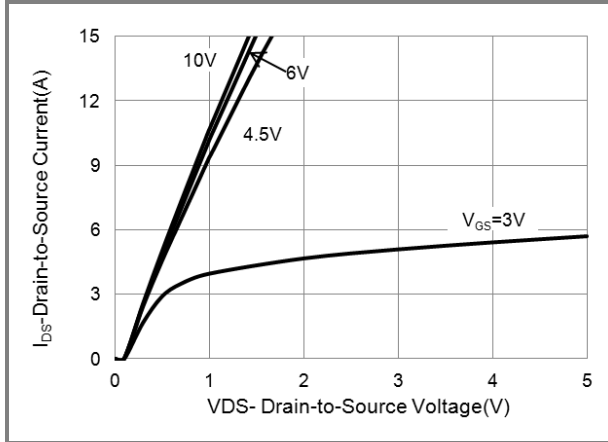


Fig.1 On-Region Characteristics

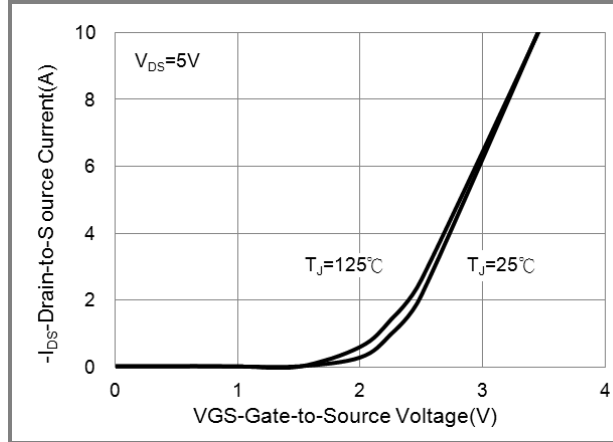


Fig.2 Transfer Characteristics

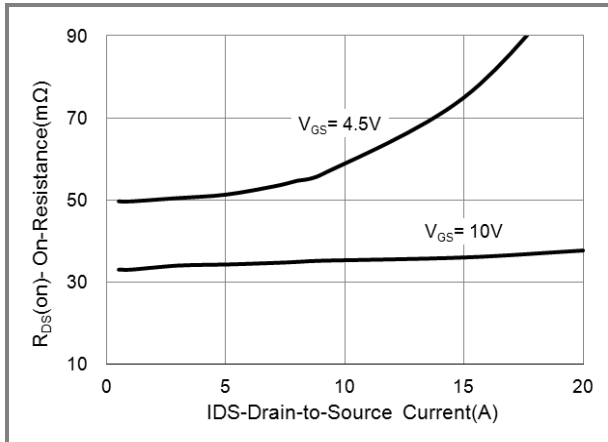


Fig.3 On-Resistance vs. Drain Current

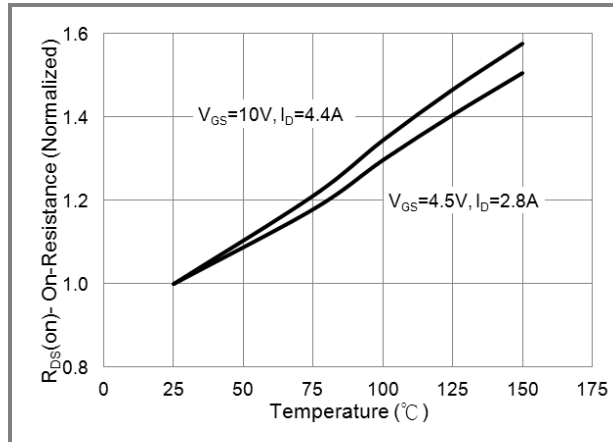


Fig.4 On-Resistance vs. Junction temperature

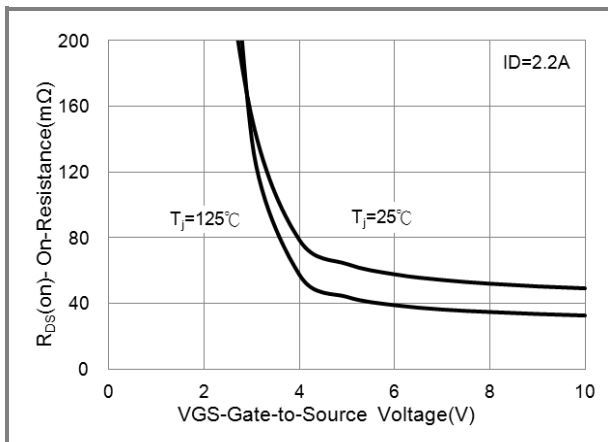


Fig.5 On-Resistance Variation with VGS.

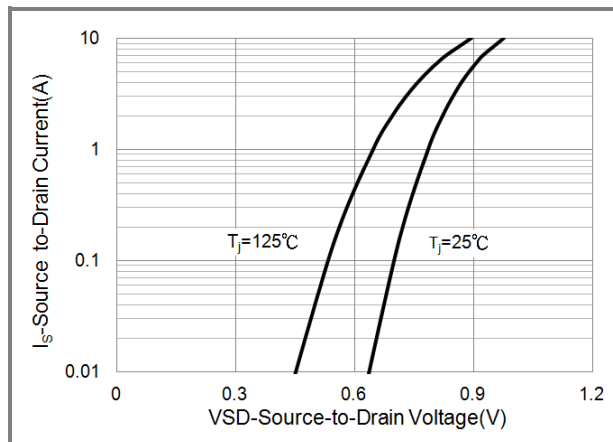


Fig.6 Body Diode Characteristics



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N-Channel TYPICAL CHARACTERISTIC CURVES

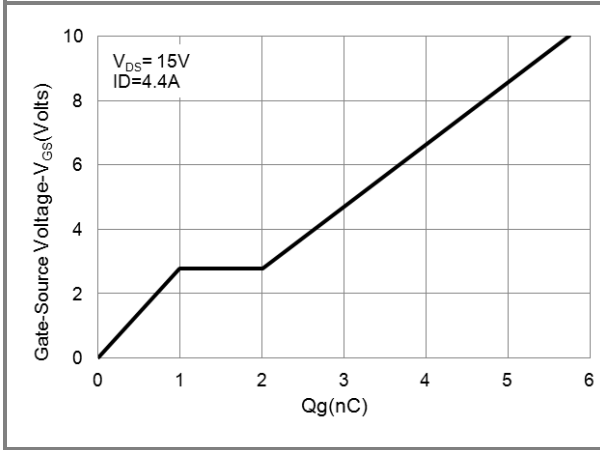


Fig.7 Gate-Charge Characteristics

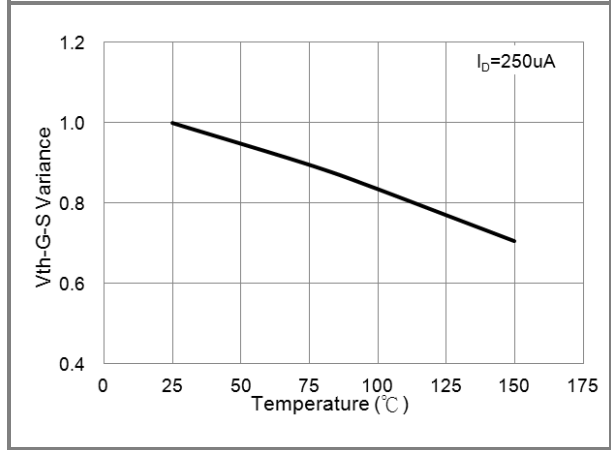


Fig.8 Threshold Voltage Variation with Temperature.

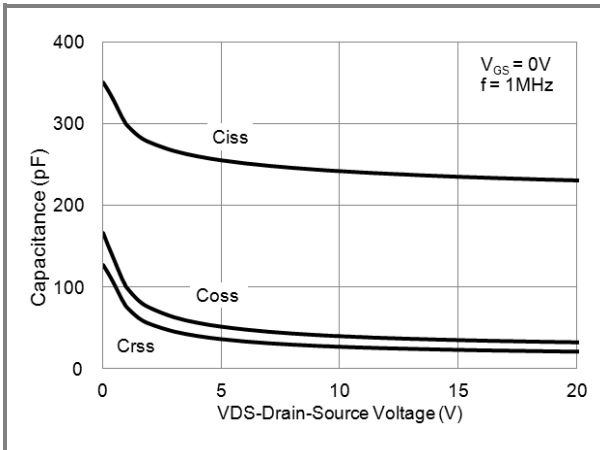


Fig.9 Capacitance vs. Drain-Source Voltage.



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P-Channel TYPICAL CHARACTERISTIC CURVES

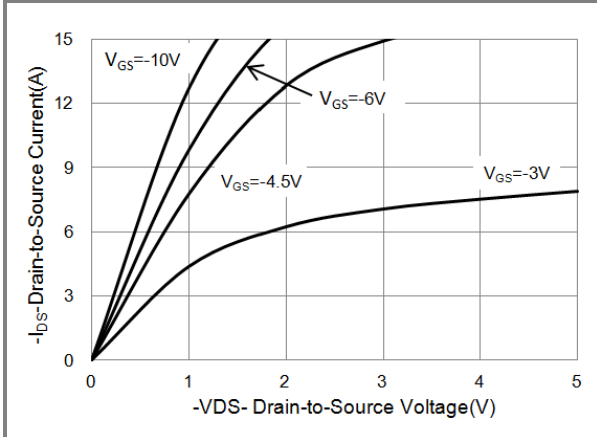


Fig.1 On-Region Characteristics

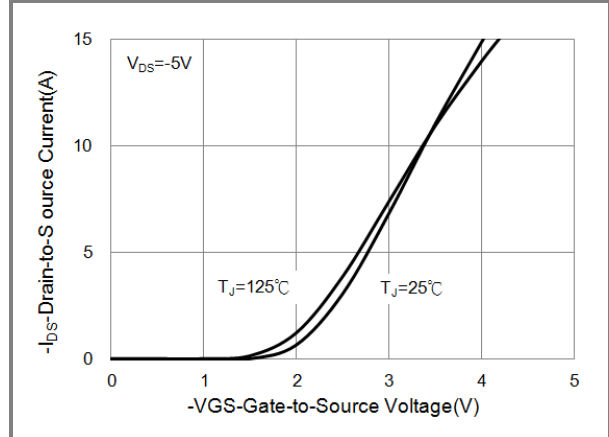


Fig.2 Transfer Characteristics

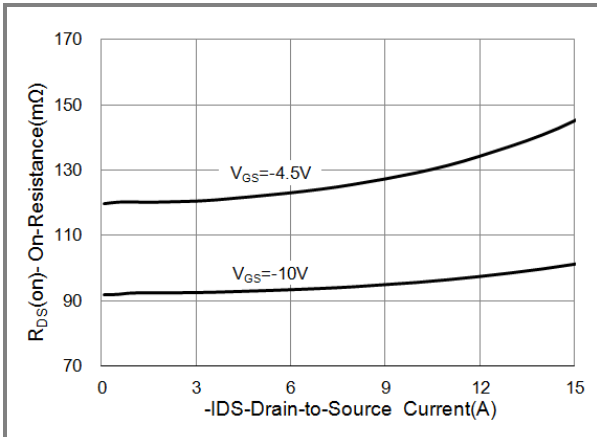


Fig.3 On-Resistance vs. Drain Current

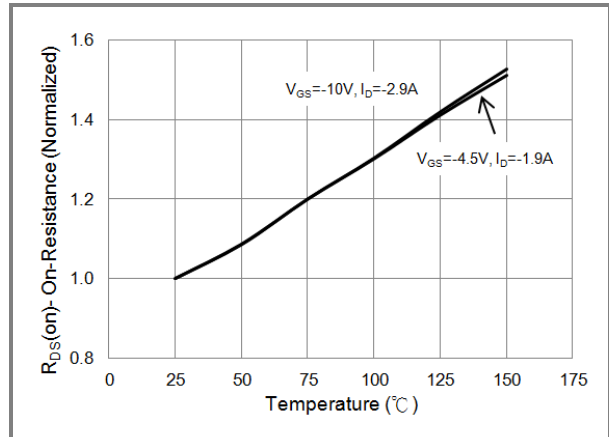


Fig.4 On-Resistance vs. Junction temperature

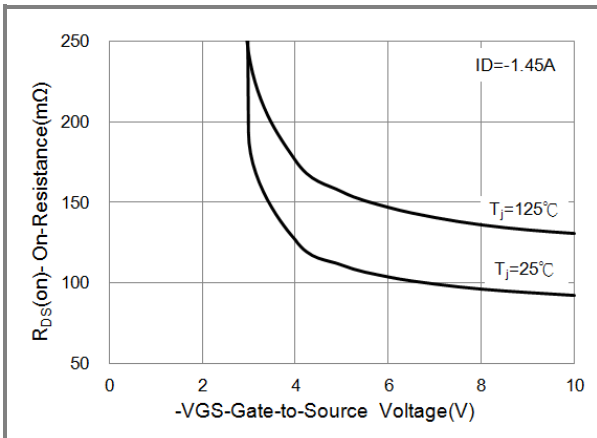


Fig.5 On-Resistance Variation with VGS.

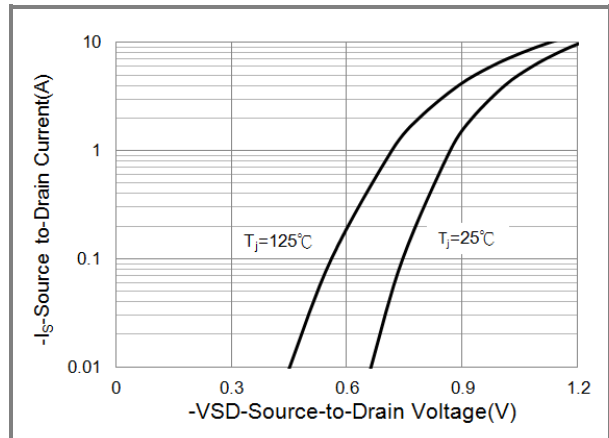


Fig.6 Body Diode Characteristics



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P-Channel TYPICAL CHARACTERISTIC CURVES

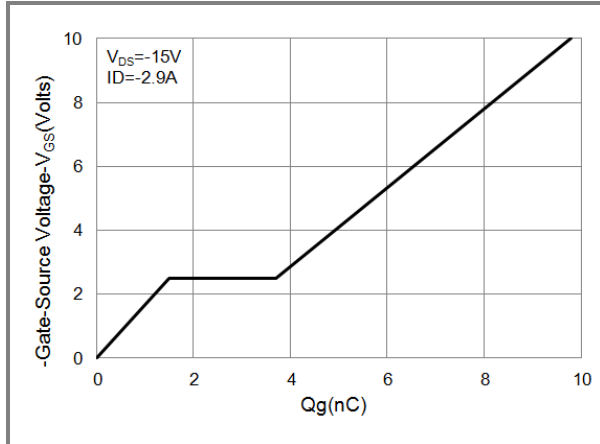


Fig.7 Gate-Charge Characteristics

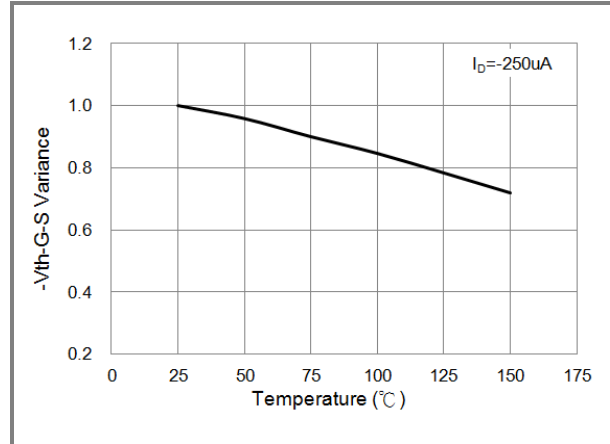


Fig.8 Threshold Voltage Variation with Temperature.

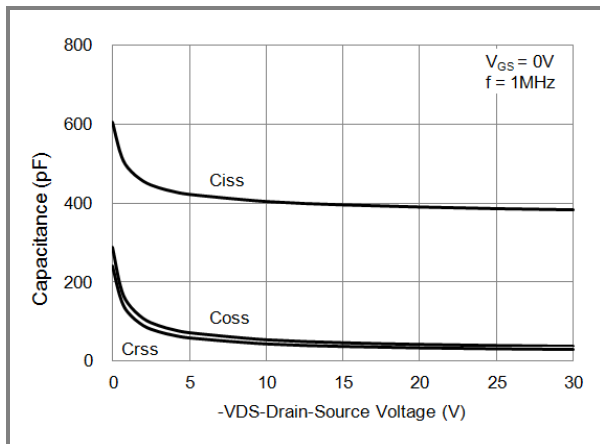


Fig.9 Threshold Voltage Variation with Temperature.

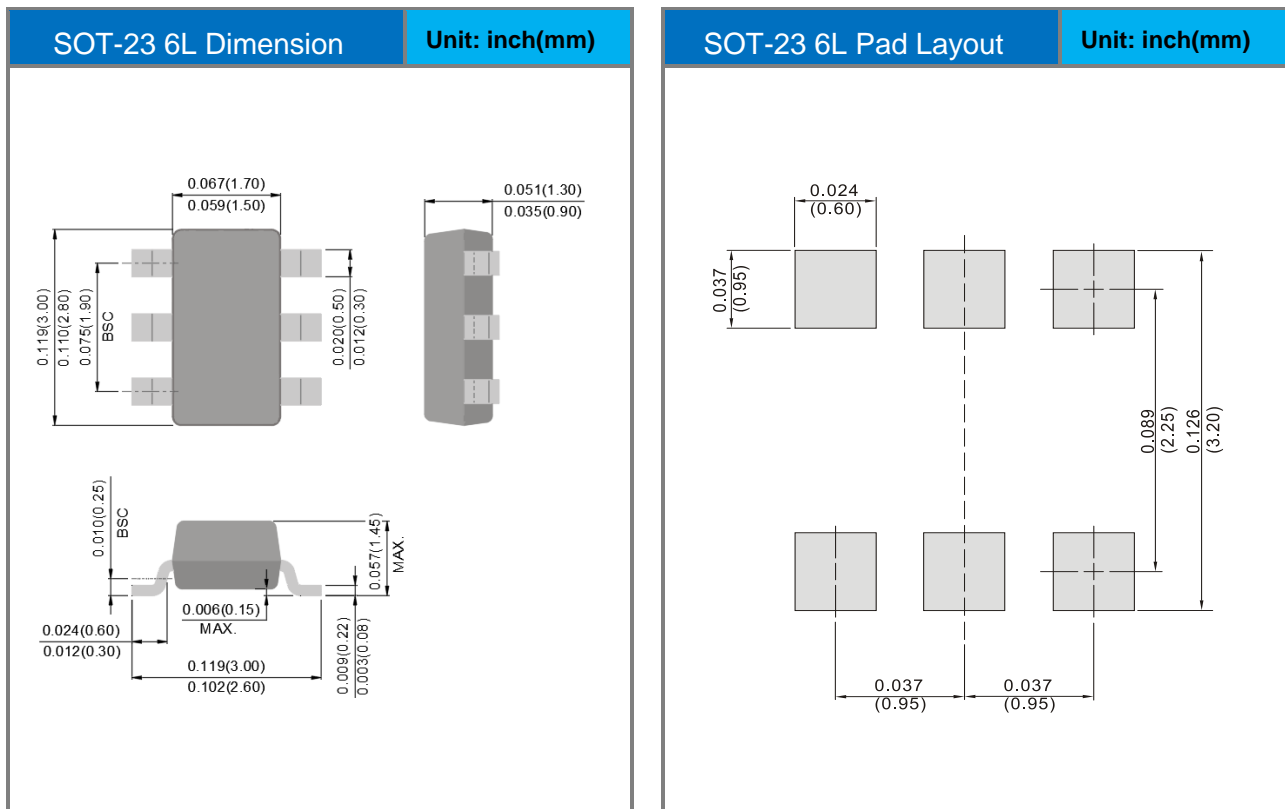


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PART NO. PACKING CODE VERSION

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJS6603-AU_S1_000A1	SOT-23 6L	3K pcs / 7" reel	SC3	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout





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